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Polymer-wrapped carbon nanotubes for high performance field effect transistors

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**Polymer-wrapped carbon
nanotubes for high performance
field effect transistors**

Volodymyr Derenskyi

Polymer-wrapped carbon nanotubes for high performance field effect transistors

Volodymyr Y. Derenskyi

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 and in accordance with
 the decision by the College of Deans.

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Tuesday 11 July 2017 at 09.00 hours

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